

# ATF-54143

## Low Noise Enhancement Mode Pseudomorphic HEMT in a Surface Mount Plastic Package



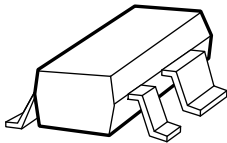
### Data Sheet

#### Description

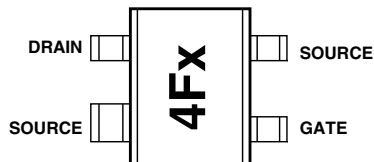
Avago Technologies' ATF-54143 is a high dynamic range, low noise, E-PHEMT housed in a 4-lead SC-70 (SOT-343) surface mount plastic package.

The combination of high gain, high linearity and low noise makes the ATF-54143 ideal for cellular/PCS base stations, MMDS, and other systems in the 450 MHz to 6 GHz frequency range.

#### Surface Mount Package SOT-343



#### Pin Connections and Package Marking



Note:

Top View. Package marking provides orientation and identification

"4F" = Device Code

"x" = Date code character  
identifies month of manufacture.

#### Features

- High linearity performance
- Enhancement Mode Technology [1]
- Low noise figure
- Excellent uniformity in product specifications
- 800 micron gate width
- Low cost surface mount small plastic package SOT-343 (4 lead SC-70)
- Tape-and-Reel packaging option available
- Lead-free option available.

#### Specifications

- 2 GHz; 3V, 60 mA (Typ.)
- 36.2 dBm output 3<sup>rd</sup> order intercept
- 20.4 dBm output power at 1 dB gain compression
- 0.5 dB noise figure
- 16.6 dB associated gain

#### Applications

- Low noise amplifier for cellular/PCS base stations
- LNA for WLAN, WLL/RLL and MMDS applications
- General purpose discrete E-PHEMT for other ultra low noise applications

Note:

1. Enhancement mode technology requires positive V<sub>gs</sub>, thereby eliminating the need for the negative gate voltage associated with conventional depletion mode devices.



**Attention: Observe precautions for handling electrostatic sensitive devices.**  
ESD Machine Model (Class A)  
ESD Human Body Model (Class 1A)  
Refer to Avago Application Note A004R:  
*Electrostatic Discharge Damage and Control.*

## ATF-54143 Absolute Maximum Ratings <sup>[1]</sup>

| Symbol                    | Parameter                                      | Units | Absolute Maximum  |
|---------------------------|--|-------|-------------------|
| $V_{DS}$                  | Drain - Source Voltage <sup>[2]</sup>          | V     | 5                 |
| $V_{GS}$                  | Gate - Source Voltage <sup>[2]</sup>           | V     | -5 to 1           |
| $V_{GD}$                  | Gate Drain Voltage <sup>[2]</sup>              | V     | -5 to 1           |
| $I_{DS}$                  | Drain Current <sup>[2]</sup>                   | mA    | 120               |
| $P_{diss}$                | Total Power Dissipation <sup>[3]</sup>         | mW    | 725               |
| $P_{in\ max.}$ (ON mode)  | RF Input Power ( $V_{ds}=3V$ , $I_{ds}=60mA$ ) | dBm   | 20 <sup>[5]</sup> |
| $P_{in\ max.}$ (OFF mode) | RF Input Power ( $V_{d}=0$ , $I_{ds}=0A$ )     | dBm   | 20                |
| $I_{GS}$                  | Gate Source Current                            | mA    | 2 <sup>[5]</sup>  |
| $T_{CH}$                  | Channel Temperature                            | °C    | 150               |
| $T_{STG}$                 | Storage Temperature                            | °C    | -65 to 150        |
| $\theta_{jc}$             | Thermal Resistance <sup>[4]</sup>              | °C/W  | 162               |

Notes:

1. Operation of this device in excess of any one of these parameters may cause permanent damage.
2. Assumes DC quiescent conditions.
3. Source lead temperature is 25°C. Derate 6.2 mW/°C for  $T_L > 33^\circ\text{C}$ .
4. Thermal resistance measured using 150°C Liquid Crystal Measurement method.
5. The device can handle +20 dBm RF Input Power provided  $I_{GS}$  is limited to 2 mA.  $I_{GS}$  at  $P_{1dB}$  drive level is bias circuit dependent. See application section for additional information.

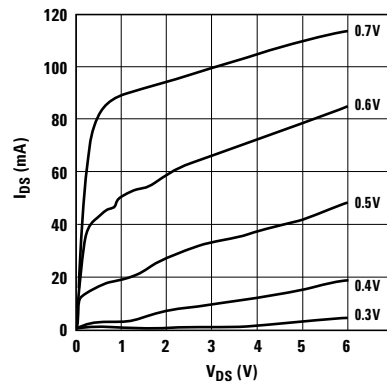


Figure 1. Typical I-V Curves.  
( $V_{GS} = 0.1\text{ V}$  per step)

## Product Consistency Distribution Charts <sup>[6, 7]</sup>

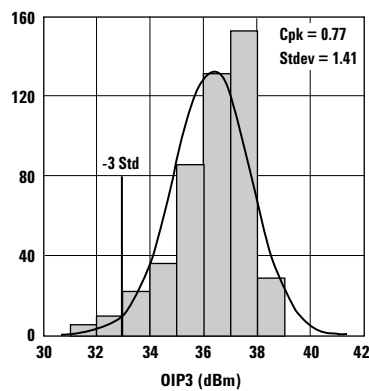


Figure 2. OIP3 @ 2 GHz, 3 V, 60 mA.  
LSL = 33.0, Nominal = 36.575

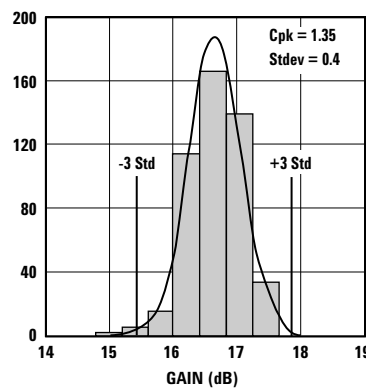


Figure 3. Gain @ 2 GHz, 3 V, 60 mA.  
USL = 18.5, LSL = 15, Nominal = 16.6

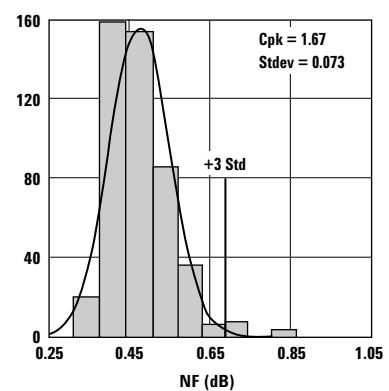


Figure 4. NF @ 2 GHz, 3 V, 60 mA.  
USL = 0.9, Nominal = 0.49

Notes:

6. Distribution data sample size is 450 samples taken from 9 different wafers. Future wafers allocated to this product may have nominal values anywhere between the upper and lower limits.
7. Measurements made on production test board. This circuit represents a trade-off between an optimal noise match and a realizable match based on production test equipment. Circuit losses have been de-embedded from actual measurements.

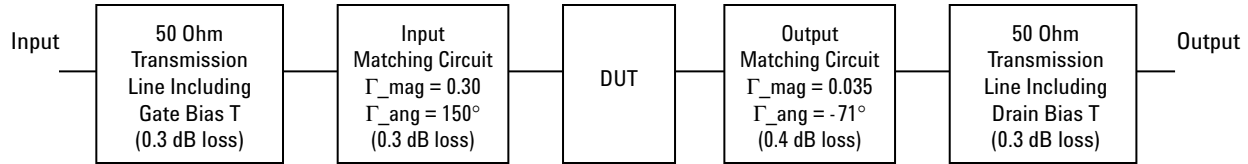
## ATF-54143 Electrical Specifications

$T_A = 25^\circ\text{C}$ , RF parameters measured in a test circuit for a typical device

| Symbol           | Parameter and Test Condition                                |  |   | Units | Min. | Typ. <sup>[2]</sup> | Max. |
|------------------|---|--|---|-------|------|---------------------|------|
| V <sub>gs</sub>  | Operational Gate Voltage                                    | V <sub>ds</sub> = 3V, I <sub>ds</sub> = 60 mA  |   | V     | 0.4  | 0.59                | 0.75 |
| V <sub>th</sub>  | Threshold Voltage   | V <sub>ds</sub> = 3V, I <sub>ds</sub> = 4 mA   |   | V     | 0.18 | 0.38                | 0.52 |
| I <sub>dss</sub> | Saturated Drain Current                                     | V <sub>ds</sub> = 3V, V <sub>gs</sub> = 0V   |   | μA    | —    | 1                   | 5    |
| G <sub>m</sub>   | Transconductance  | V <sub>ds</sub> = 3V, $g_m = \Delta I_{dss} / \Delta V_{gs}$ ; $\Delta V_{gs} = 0.75 - 0.7 = 0.05\text{V}$ |   | mmho  | 230  | 410                 | 560  |
| I <sub>gss</sub> | Gate Leakage Current  | V <sub>gd</sub> = V <sub>gs</sub> = -3V  |   | μA    | —    | —                   | 200  |
| NF               | Noise Figure <sup>[1]</sup>                                 | f = 2 GHz  | V <sub>ds</sub> = 3V, I <sub>ds</sub> = 60 mA | dB    | —    | 0.5                 | 0.9  |
|                  |   | f = 900 MHz  | V <sub>ds</sub> = 3V, I <sub>ds</sub> = 60 mA | dB    | —    | 0.3                 | —    |
| G <sub>a</sub>   | Associated Gain <sup>[1]</sup>                              | f = 2 GHz  | V <sub>ds</sub> = 3V, I <sub>ds</sub> = 60 mA | dB    | 15   | 16.6                | 18.5 |
|                  |   | f = 900 MHz  | V <sub>ds</sub> = 3V, I <sub>ds</sub> = 60 mA | dB    | —    | 23.4                | —    |
| OIP3             | Output 3 <sup>rd</sup> Order Intercept Point <sup>[1]</sup> | f = 2 GHz  | V <sub>ds</sub> = 3V, I <sub>ds</sub> = 60 mA | dBm   | 33   | 36.2                | —    |
|                  |   | f = 900 MHz  | V <sub>ds</sub> = 3V, I <sub>ds</sub> = 60 mA | dBm   | —    | 35.5                | —    |
| P1dB             | 1dB Compressed Output Power <sup>[1]</sup>                  | f = 2 GHz  | V <sub>ds</sub> = 3V, I <sub>ds</sub> = 60 mA | dBm   | —    | 20.4                | —    |
|                  |   | f = 900 MHz  | V <sub>ds</sub> = 3V, I <sub>ds</sub> = 60 mA | dBm   | —    | 18.4                | —    |

Notes:

- Measurements obtained using production test board described in Figure 5.
- Typical values measured from a sample size of 450 parts from 9 wafers.



**Figure 5. Block diagram of 2 GHz production test board used for Noise Figure, Associated Gain, P1dB, and OIP3 measurements. This circuit represents a trade-off between an optimal noise match and associated impedance matching circuit losses. Circuit losses have been de-embedded from actual measurements.**

## ATF-54143 Typical Performance Curves

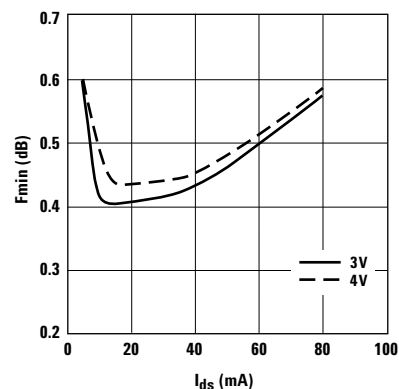


Figure 6. Fmin vs.  $I_{ds}$  and  $V_{ds}$  Tuned for Max OIP3 and Fmin at 2 GHz.

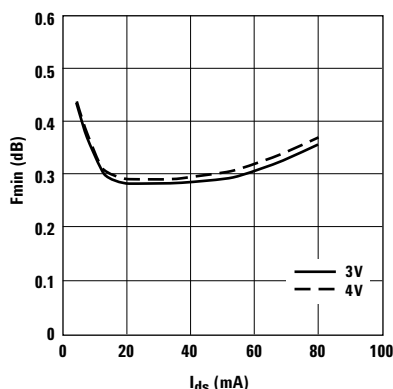


Figure 7. Fmin vs.  $I_{ds}$  and  $V_{ds}$  Tuned for Max OIP3 and Min NF at 900 MHz.

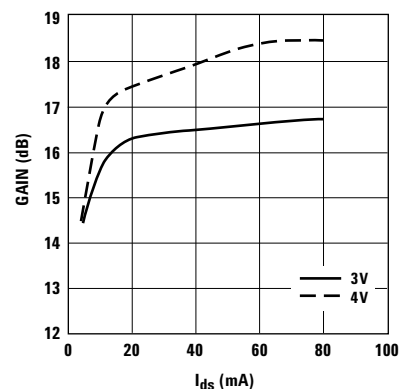


Figure 8. Gain vs.  $I_{ds}$  and  $V_{ds}$  Tuned for Max OIP3 and Fmin at 2 GHz.

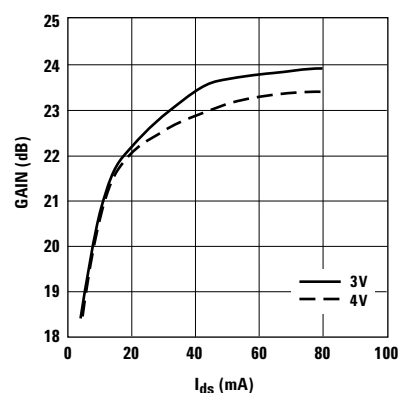


Figure 9. Gain vs.  $I_{ds}$  and  $V_{ds}$  Tuned for Max OIP3 and Fmin at 900 MHz.

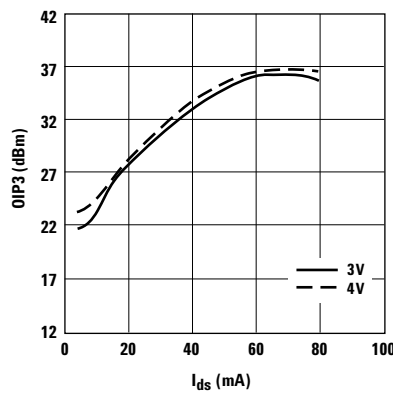


Figure 10. OIP3 vs.  $I_{ds}$  and  $V_{ds}$  Tuned for Max OIP3 and Fmin at 2 GHz.

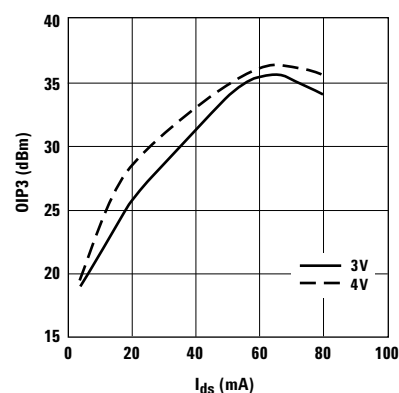


Figure 11. OIP3 vs.  $I_{ds}$  and  $V_{ds}$  Tuned for Max OIP3 and Fmin at 900 MHz.

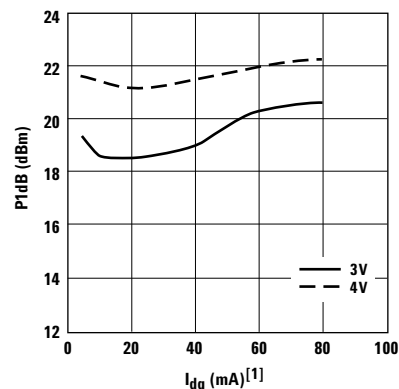


Figure 12. P1dB vs.  $I_{dq}$  and  $V_{ds}$  Tuned for Max OIP3 and Fmin at 2 GHz.

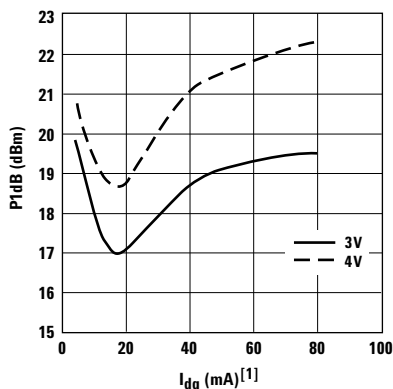


Figure 13. P1dB vs.  $I_{dq}$  and  $V_{ds}$  Tuned for Max OIP3 and Fmin at 900 MHz.

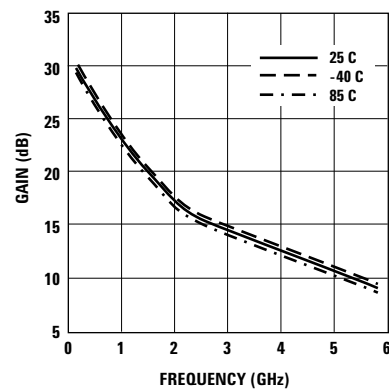


Figure 14. Gain vs. Frequency and Temp Tuned for Max OIP3 and Fmin at 3V, 60 mA.

### Notes:

1.  $I_{dq}$  represents the quiescent drain current without RF drive applied. Under low values of  $I_{ds}$ , the application of RF drive will cause  $I_d$  to increase substantially as P1dB is approached.
2. Fmin values at 2 GHz and higher are based on measurements while the Fmins below 2 GHz have been extrapolated. The Fmin values are based on a set of 16 noise figure measurements made at 16 different impedances using an ATN NP5 test system. From these measurements a true Fmin is calculated. Refer to the noise parameter application section for more information.

## ATF-54143 Typical Performance Curves, continued

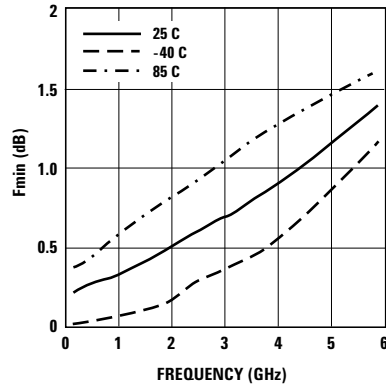


Figure 15.  $F_{min}^{[2]}$  vs. Frequency and Temp Tuned for Max OIP3 and  $F_{min}$  at 3V, 60 mA.

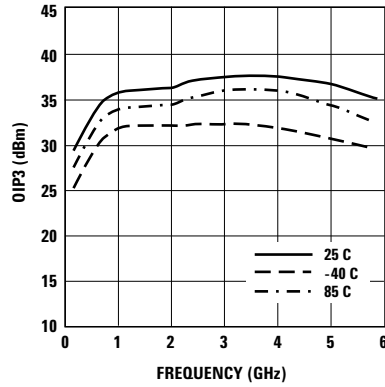


Figure 16. OIP3 vs. Frequency and Temp Tuned for Max OIP3 and  $F_{min}$  at 3V, 60 mA.

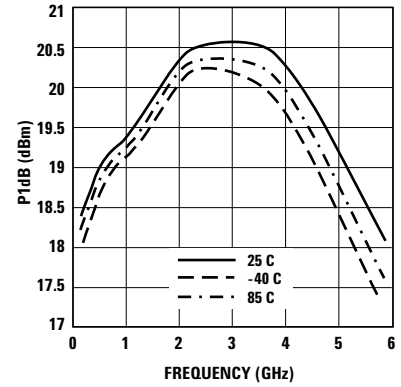


Figure 17. P1dB vs. Frequency and Temp Tuned for Max OIP3 and  $F_{min}$  at 3V, 60 mA.

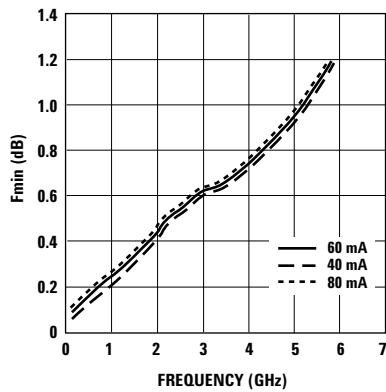


Figure 18.  $F_{min}^{[1]}$  vs. Frequency and  $I_{ds}$  at 3V.

## ATF-54143 Reflection Coefficient Parameters tuned for Maximum Output IP3, $V_{DS} = 3V$ , $I_{DS} = 60 mA$

| Freq (GHz) | $\Gamma_{Out\_Mag}^{[1]}$ (Mag) | $\Gamma_{Out\_Ang}^{[2]}$ (Degrees) | OIP3 (dBm) | P1dB (dBm) |
|------------|---------------------------------|-------------------------------------|------------|------------|
| 0.9        | 0.017                           | 115                                 | 35.54      | 18.4       |
| 2.0        | 0.026                           | -85                                 | 36.23      | 20.38      |
| 3.9        | 0.013                           | 173                                 | 37.54      | 20.28      |
| 5.8        | 0.025                           | 102                                 | 35.75      | 18.09      |

Note:

- Gamma out is the reflection coefficient of the matching circuit presented to the output of the device.
- $F_{min}$  values at 2 GHz and higher are based on measurements while the  $F_{min}$ s below 2 GHz have been extrapolated. The  $F_{min}$  values are based on a set of 16 noise figure measurements made at 16 different impedances using an ATN NP5 test system. From these measurements a true  $F_{min}$  is calculated. Refer to the noise parameter application section for more information.

# ATF-54143 Typical Scattering Parameters, $V_{DS} = 3V$ , $I_{DS} = 40\text{ mA}$

| Freq.<br>GHz | $S_{11}$ |        |       | $S_{21}$ |        | $S_{12}$ |        | $S_{22}$ |        | MSG/MAG<br>dB |
|--------------|----------|--------|-------|----------|--------|----------|--------|----------|--------|---------------|
|              | Mag.     | Ang.   | dB    | Mag.     | Ang.   | Mag.     | Ang.   | Mag.     | Ang.   |               |
| 0.1          | 0.99     | -17.6  | 27.99 | 25.09    | 168.5  | 0.009    | 80.2   | 0.59     | -12.8  | 34.45         |
| 0.5          | 0.83     | -76.9  | 25.47 | 18.77    | 130.1  | 0.036    | 52.4   | 0.44     | -54.6  | 27.17         |
| 0.9          | 0.72     | -114   | 22.52 | 13.37    | 108    | 0.047    | 40.4   | 0.33     | -78.7  | 24.54         |
| 1.0          | 0.70     | -120.6 | 21.86 | 12.39    | 103.9  | 0.049    | 38.7   | 0.31     | -83.2  | 24.03         |
| 1.5          | 0.65     | -146.5 | 19.09 | 9.01     | 87.4   | 0.057    | 33.3   | 0.24     | -99.5  | 21.99         |
| 1.9          | 0.63     | -162.1 | 17.38 | 7.40     | 76.6   | 0.063    | 30.4   | 0.20     | -108.6 | 20.70         |
| 2.0          | 0.62     | -165.6 | 17.00 | 7.08     | 74.2   | 0.065    | 29.8   | 0.19     | -110.9 | 20.37         |
| 2.5          | 0.61     | 178.5  | 15.33 | 5.84     | 62.6   | 0.072    | 26.6   | 0.15     | -122.6 | 19.09         |
| 3.0          | 0.61     | 164.2  | 13.91 | 4.96     | 51.5   | 0.080    | 22.9   | 0.12     | -137.5 | 17.92         |
| 4.0          | 0.63     | 138.4  | 11.59 | 3.80     | 31     | 0.094    | 14     | 0.10     | 176.5  | 15.33         |
| 5.0          | 0.66     | 116.5  | 9.65  | 3.04     | 11.6   | 0.106    | 4.2    | 0.14     | 138.4  | 12.99         |
| 6.0          | 0.69     | 97.9   | 8.01  | 2.51     | -6.7   | 0.118    | -6.1   | 0.17     | 117.6  | 11.50         |
| 7.0          | 0.71     | 80.8   | 6.64  | 2.15     | -24.5  | 0.128    | -17.6  | 0.20     | 98.6   | 10.24         |
| 8.0          | 0.72     | 62.6   | 5.38  | 1.86     | -42.5  | 0.134    | -29.3  | 0.22     | 73.4   | 8.83          |
| 9.0          | 0.76     | 45.2   | 4.20  | 1.62     | -60.8  | 0.145    | -40.6  | 0.27     | 52.8   | 8.17          |
| 10.0         | 0.83     | 28.2   | 2.84  | 1.39     | -79.8  | 0.150    | -56.1  | 0.37     | 38.3   | 8.57          |
| 11.0         | 0.85     | 13.9   | 1.42  | 1.18     | -96.9  | 0.149    | -69.3  | 0.45     | 25.8   | 7.47          |
| 12.0         | 0.88     | -0.5   | 0.23  | 1.03     | -112.4 | 0.150    | -81.6  | 0.51     | 12.7   | 7.50          |
| 13.0         | 0.89     | -15.1  | -0.86 | 0.91     | -129.7 | 0.149    | -95.7  | 0.54     | -4.1   | 6.60          |
| 14.0         | 0.87     | -31.6  | -2.18 | 0.78     | -148   | 0.143    | -110.3 | 0.61     | -20.1  | 4.57          |
| 15.0         | 0.88     | -46.1  | -3.85 | 0.64     | -164.8 | 0.132    | -124   | 0.65     | -34.9  | 3.47          |
| 16.0         | 0.87     | -54.8  | -5.61 | 0.52     | -178.4 | 0.121    | -134.6 | 0.70     | -45.6  | 2.04          |
| 17.0         | 0.87     | -62.8  | -7.09 | 0.44     | 170.1  | 0.116    | -144.1 | 0.73     | -55.9  | 1.05          |
| 18.0         | 0.92     | -73.6  | -8.34 | 0.38     | 156.1  | 0.109    | -157.4 | 0.76     | -68.7  | 1.90          |

## Typical Noise Parameters, $V_{DS} = 3V$ , $I_{DS} = 40\text{ mA}$

| Freq<br>GHz | $F_{min}$<br>dB | $\Gamma_{opt}$<br>Mag. | $\Gamma_{opt}$<br>Ang. | $R_n/50$ | $G_a$<br>dB |
|-------------|-----------------|------------------------|------------------------|----------|-------------|
| 0.5         | 0.17            | 0.34                   | 34.80                  | 0.04     | 27.83       |
| 0.9         | 0.22            | 0.32                   | 53.00                  | 0.04     | 23.57       |
| 1.0         | 0.24            | 0.32                   | 60.50                  | 0.04     | 22.93       |
| 1.9         | 0.42            | 0.29                   | 108.10                 | 0.04     | 18.35       |
| 2.0         | 0.45            | 0.29                   | 111.10                 | 0.04     | 17.91       |
| 2.4         | 0.51            | 0.30                   | 136.00                 | 0.04     | 16.39       |
| 3.0         | 0.59            | 0.32                   | 169.90                 | 0.05     | 15.40       |
| 3.9         | 0.69            | 0.34                   | -151.60                | 0.05     | 13.26       |
| 5.0         | 0.90            | 0.45                   | -119.50                | 0.09     | 11.89       |
| 5.8         | 1.14            | 0.50                   | -101.60                | 0.16     | 10.95       |
| 6.0         | 1.17            | 0.52                   | -99.60                 | 0.18     | 10.64       |
| 7.0         | 1.24            | 0.58                   | -79.50                 | 0.33     | 9.61        |
| 8.0         | 1.57            | 0.60                   | -57.90                 | 0.56     | 8.36        |
| 9.0         | 1.64            | 0.69                   | -39.70                 | 0.87     | 7.77        |
| 10.0        | 1.8             | 0.80                   | -22.20                 | 1.34     | 7.68        |

### Notes:

1.  $F_{min}$  values at 2 GHz and higher are based on measurements while the  $F_{min}$ s below 2 GHz have been extrapolated. The  $F_{min}$  values are based on a set of 16 noise figure measurements made at 16 different impedances using an ATN NP5 test system. From these measurements a true  $F_{min}$  is calculated. Refer to the noise parameter application section for more information.
2. S and noise parameters are measured on a microstrip line made on 0.025 inch thick alumina carrier. The input reference plane is at the end of the gate lead. The output reference plane is at the end of the drain lead. The parameters include the effect of four plated through via holes connecting source landing pads on top of the test carrier to the microstrip ground plane on the bottom side of the carrier. Two 0.020 inch diameter via holes are placed within 0.010 inch from each source lead contact point, one via on each side of that point.

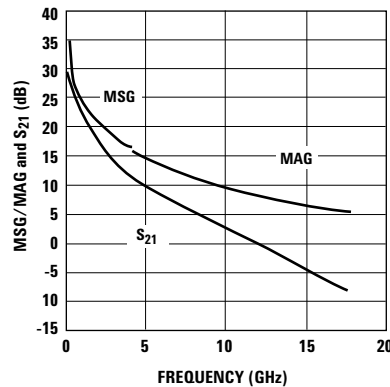


Figure 19. MSG/MAG and  $|S_{21}|^2$  vs. Frequency at 3V, 40 mA.

# ATF-54143 Typical Scattering Parameters, $V_{DS} = 3V$ , $I_{DS} = 60\text{ mA}$

| Freq.<br>GHz | $S_{11}$ |        |       | $S_{21}$ |        | $S_{12}$ |        | $S_{22}$ |        | MSG/MAG<br>dB |
|--------------|----------|--------|-------|----------|--------|----------|--------|----------|--------|---------------|
|              | Mag.     | Ang.   | dB    | Mag.     | Ang.   | Mag.     | Ang.   | Mag.     | Ang.   |               |
| 0.1          | 0.99     | -18.9  | 28.84 | 27.66    | 167.6  | 0.01     | 80.0   | 0.54     | -14.0  | 34.42         |
| 0.5          | 0.81     | -80.8  | 26.04 | 20.05    | 128.0  | 0.03     | 52.4   | 0.40     | -58.8  | 28.25         |
| 0.9          | 0.71     | -117.9 | 22.93 | 14.01    | 106.2  | 0.04     | 41.8   | 0.29     | -83.8  | 25.44         |
| 1.0          | 0.69     | -124.4 | 22.24 | 12.94    | 102.2  | 0.05     | 40.4   | 0.27     | -88.5  | 24.13         |
| 1.5          | 0.64     | -149.8 | 19.40 | 9.34     | 86.1   | 0.05     | 36.1   | 0.21     | -105.2 | 22.71         |
| 1.9          | 0.62     | -164.9 | 17.66 | 7.64     | 75.6   | 0.06     | 33.8   | 0.17     | -114.7 | 21.05         |
| 2.0          | 0.62     | -168.3 | 17.28 | 7.31     | 73.3   | 0.06     | 33.3   | 0.17     | -117.0 | 20.86         |
| 2.5          | 0.60     | 176.2  | 15.58 | 6.01     | 61.8   | 0.07     | 30.1   | 0.13     | -129.7 | 19.34         |
| 3.0          | 0.60     | 162.3  | 14.15 | 5.10     | 51.0   | 0.08     | 26.5   | 0.11     | -146.5 | 18.04         |
| 4.0          | 0.62     | 137.1  | 11.81 | 3.90     | 30.8   | 0.09     | 17.1   | 0.10     | 165.2  | 14.87         |
| 5.0          | 0.66     | 115.5  | 9.87  | 3.11     | 11.7   | 0.11     | 6.8    | 0.14     | 131.5  | 13.27         |
| 6.0          | 0.69     | 97.2   | 8.22  | 2.58     | -6.4   | 0.12     | -3.9   | 0.18     | 112.4  | 11.72         |
| 7.0          | 0.70     | 80.2   | 6.85  | 2.20     | -24.0  | 0.13     | -15.8  | 0.20     | 94.3   | 10.22         |
| 8.0          | 0.72     | 62.2   | 5.58  | 1.90     | -41.8  | 0.14     | -28.0  | 0.23     | 70.1   | 9.02          |
| 9.0          | 0.76     | 45.0   | 4.40  | 1.66     | -59.9  | 0.15     | -39.6  | 0.29     | 50.6   | 8.38          |
| 10.0         | 0.83     | 28.4   | 3.06  | 1.42     | -78.7  | 0.15     | -55.1  | 0.38     | 36.8   | 8.71          |
| 11.0         | 0.85     | 13.9   | 1.60  | 1.20     | -95.8  | 0.15     | -68.6  | 0.46     | 24.4   | 7.55          |
| 12.0         | 0.88     | -0.2   | 0.43  | 1.05     | -111.1 | 0.15     | -80.9  | 0.51     | 11.3   | 7.55          |
| 13.0         | 0.89     | -14.6  | -0.65 | 0.93     | -128.0 | 0.15     | -94.9  | 0.55     | -5.2   | 6.70          |
| 14.0         | 0.88     | -30.6  | -1.98 | 0.80     | -146.1 | 0.14     | -109.3 | 0.61     | -20.8  | 5.01          |
| 15.0         | 0.88     | -45.0  | -3.62 | 0.66     | -162.7 | 0.13     | -122.9 | 0.66     | -35.0  | 3.73          |
| 16.0         | 0.88     | -54.5  | -5.37 | 0.54     | -176.6 | 0.12     | -133.7 | 0.70     | -45.8  | 2.54          |
| 17.0         | 0.88     | -62.5  | -6.83 | 0.46     | 171.9  | 0.12     | -143.2 | 0.73     | -56.1  | 1.57          |
| 18.0         | 0.92     | -73.4  | -8.01 | 0.40     | 157.9  | 0.11     | -156.3 | 0.76     | -68.4  | 2.22          |

## Typical Noise Parameters, $V_{DS} = 3V$ , $I_{DS} = 60\text{ mA}$

| Freq<br>GHz | $F_{min}$<br>dB | $\Gamma_{opt}$<br>Mag. | $\Gamma_{opt}$<br>Ang. | $R_n/50$ | $G_a$<br>dB |
|-------------|-----------------|------------------------|------------------------|----------|-------------|
| 0.5         | 0.15            | 0.34                   | 42.3                   | 0.04     | 28.50       |
| 0.9         | 0.20            | 0.32                   | 62.8                   | 0.04     | 24.18       |
| 1.0         | 0.22            | 0.32                   | 67.6                   | 0.04     | 23.47       |
| 1.9         | 0.42            | 0.27                   | 116.3                  | 0.04     | 18.67       |
| 2.0         | 0.45            | 0.27                   | 120.1                  | 0.04     | 18.29       |
| 2.4         | 0.52            | 0.26                   | 145.8                  | 0.04     | 16.65       |
| 3.0         | 0.59            | 0.29                   | 178.0                  | 0.05     | 15.56       |
| 3.9         | 0.70            | 0.36                   | -145.4                 | 0.05     | 13.53       |
| 5.0         | 0.93            | 0.47                   | -116.0                 | 0.10     | 12.13       |
| 5.8         | 1.16            | 0.52                   | -98.9                  | 0.18     | 11.10       |
| 6.0         | 1.19            | 0.55                   | -96.5                  | 0.20     | 10.95       |
| 7.0         | 1.26            | 0.60                   | -77.1                  | 0.37     | 9.73        |
| 8.0         | 1.63            | 0.62                   | -56.1                  | 0.62     | 8.56        |
| 9.0         | 1.69            | 0.70                   | -38.5                  | 0.95     | 7.97        |
| 10.0        | 1.73            | 0.79                   | -21.5                  | 1.45     | 7.76        |

Notes:

1.  $F_{min}$  values at 2 GHz and higher are based on measurements while the  $F_{min}$ s below 2 GHz have been extrapolated. The  $F_{min}$  values are based on a set of 16 noise figure measurements made at 16 different impedances using an ATN NP5 test system. From these measurements a true  $F_{min}$  is calculated. Refer to the noise parameter application section for more information.
2.  $S$  and noise parameters are measured on a microstrip line made on 0.025 inch thick alumina carrier. The input reference plane is at the end of the gate lead. The output reference plane is at the end of the drain lead. The parameters include the effect of four plated through via holes connecting source landing pads on top of the test carrier to the microstrip ground plane on the bottom side of the carrier. Two 0.020 inch diameter via holes are placed within 0.010 inch from each source lead contact point, one via on each side of that point.

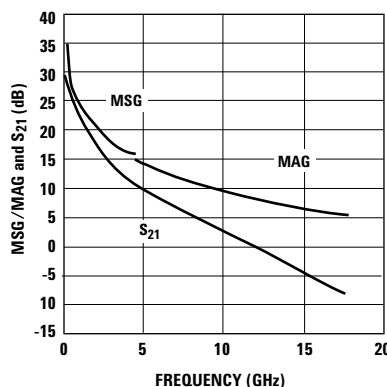


Figure 20. MSG/MAG and  $|S_{21}|^2$  vs. Frequency at 3V, 60 mA.

# ATF-54143 Typical Scattering Parameters, $V_{DS} = 3V$ , $I_{DS} = 80\text{ mA}$

| Freq.<br>GHz | $S_{11}$ |        |       | $S_{21}$ |        | $S_{12}$ |        | $S_{22}$ |        | MSG/MAG<br>dB |
|--------------|----------|--------|-------|----------|--------|----------|--------|----------|--------|---------------|
|              | Mag.     | Ang.   | dB    | Mag.     | Ang.   | Mag.     | Ang.   | Mag.     | Ang.   |               |
| 0.1          | 0.98     | -20.4  | 28.32 | 26.05    | 167.1  | 0.01     | 79.4   | 0.26     | -27.6  | 34.16         |
| 0.5          | 0.80     | -85.9  | 25.32 | 18.45    | 126.8  | 0.04     | 53.3   | 0.29     | -104.9 | 26.64         |
| 0.9          | 0.72     | -123.4 | 22.10 | 12.73    | 105.2  | 0.05     | 43.9   | 0.30     | -138.8 | 24.06         |
| 1.0          | 0.70     | -129.9 | 21.40 | 11.75    | 101.3  | 0.05     | 42.7   | 0.30     | -144.3 | 23.71         |
| 1.5          | 0.66     | -154.6 | 18.55 | 8.46     | 85.4   | 0.06     | 38.6   | 0.30     | -165.0 | 21.49         |
| 1.9          | 0.65     | -169.5 | 16.81 | 6.92     | 74.9   | 0.07     | 35.7   | 0.29     | -177.6 | 19.95         |
| 2.0          | 0.64     | -172.8 | 16.42 | 6.62     | 72.6   | 0.07     | 35.0   | 0.29     | -179.4 | 19.76         |
| 2.5          | 0.64     | 172.1  | 14.69 | 5.42     | 61.1   | 0.09     | 30.6   | 0.29     | 164.4  | 17.80         |
| 3.0          | 0.63     | 158.5  | 13.24 | 4.59     | 50.1   | 0.10     | 25.5   | 0.29     | 150.2  | 16.62         |
| 4.0          | 0.66     | 133.8  | 10.81 | 3.47     | 29.9   | 0.12     | 13.4   | 0.33     | 126.1  | 14.61         |
| 5.0          | 0.69     | 112.5  | 8.74  | 2.74     | 11.1   | 0.13     | 1.2    | 0.39     | 107.8  | 12.03         |
| 6.0          | 0.72     | 94.3   | 7.03  | 2.25     | -6.5   | 0.14     | -11.3  | 0.42     | 91.8   | 10.52         |
| 7.0          | 0.73     | 77.4   | 5.63  | 1.91     | -23.5  | 0.15     | -24.5  | 0.44     | 75.5   | 9.12          |
| 8.0          | 0.74     | 59.4   | 4.26  | 1.63     | -41.1  | 0.16     | -38.1  | 0.47     | 55.5   | 7.78          |
| 9.0          | 0.78     | 42.1   | 2.98  | 1.41     | -58.7  | 0.17     | -51.1  | 0.52     | 37.8   | 7.12          |
| 10.0         | 0.84     | 25.6   | 1.51  | 1.19     | -76.4  | 0.16     | -66.8  | 0.59     | 24.0   | 6.96          |
| 11.0         | 0.86     | 11.4   | 0.00  | 1.00     | -92.0  | 0.16     | -79.8  | 0.64     | 11.8   | 6.11          |
| 12.0         | 0.88     | -2.6   | -1.15 | 0.88     | -105.9 | 0.16     | -91.7  | 0.68     | -0.8   | 5.67          |
| 13.0         | 0.89     | -17.0  | -2.18 | 0.78     | -121.7 | 0.15     | -105.6 | 0.70     | -16.7  | 5.08          |
| 14.0         | 0.87     | -33.3  | -3.48 | 0.67     | -138.7 | 0.14     | -119.5 | 0.73     | -31.7  | 3.67          |
| 15.0         | 0.87     | -47.3  | -5.02 | 0.56     | -153.9 | 0.13     | -132.3 | 0.76     | -44.9  | 2.65          |
| 16.0         | 0.86     | -55.6  | -6.65 | 0.47     | -165.9 | 0.12     | -141.7 | 0.78     | -54.9  | 1.48          |
| 17.0         | 0.86     | -63.4  | -7.92 | 0.40     | -175.9 | 0.11     | -150.4 | 0.79     | -64.2  | 0.49          |
| 18.0         | 0.91     | -74.2  | -8.92 | 0.36     | 171.2  | 0.10     | -163.0 | 0.81     | -76.2  | 1.29          |

## Typical Noise Parameters, $V_{DS} = 3V$ , $I_{DS} = 80\text{ mA}$

| Freq<br>GHz | $F_{min}$ | $\Gamma_{opt}$ | $\Gamma_{opt}$ | $R_n/50$ | $G_a$ |
|-------------|-----------|----------------|----------------|----------|-------|
|             | dB        | Mag.           | Ang.           |          |       |
| 0.5         | 0.19      | 0.23           | 66.9           | 0.04     | 27.93 |
| 0.9         | 0.24      | 0.24           | 84.3           | 0.04     | 24.13 |
| 1.0         | 0.25      | 0.25           | 87.3           | 0.04     | 23.30 |
| 1.9         | 0.43      | 0.28           | 134.8          | 0.04     | 18.55 |
| 2.0         | 0.42      | 0.29           | 138.8          | 0.04     | 18.15 |
| 2.4         | 0.51      | 0.30           | 159.5          | 0.03     | 16.44 |
| 3.0         | 0.61      | 0.35           | -173           | 0.03     | 15.13 |
| 3.9         | 0.70      | 0.41           | -141.6         | 0.06     | 12.97 |
| 5.0         | 0.94      | 0.52           | -113.5         | 0.13     | 11.42 |
| 5.8         | 1.20      | 0.56           | -97.1          | 0.23     | 10.48 |
| 6.0         | 1.26      | 0.58           | -94.8          | 0.26     | 10.11 |
| 7.0         | 1.34      | 0.62           | -75.8          | 0.46     | 8.86  |
| 8.0         | 1.74      | 0.63           | -55.5          | 0.76     | 7.59  |
| 9.0         | 1.82      | 0.71           | -37.7          | 1.17     | 6.97  |
| 10.0        | 1.94      | 0.79           | -20.8          | 1.74     | 6.65  |

### Notes:

1.  $F_{min}$  values at 2 GHz and higher are based on measurements while the  $F_{min}$ s below 2 GHz have been extrapolated. The  $F_{min}$  values are based on a set of 16 noise figure measurements made at 16 different impedances using an ATN NP5 test system. From these measurements a true  $F_{min}$  is calculated. Refer to the noise parameter application section for more information.
2. S and noise parameters are measured on a microstrip line made on 0.025 inch thick alumina carrier. The input reference plane is at the end of the gate lead. The output reference plane is at the end of the drain lead. The parameters include the effect of four plated through via holes connecting source landing pads on top of the test carrier to the microstrip ground plane on the bottom side of the carrier. Two 0.020 inch diameter via holes are placed within 0.010 inch from each source lead contact point, one via on each side of that point.

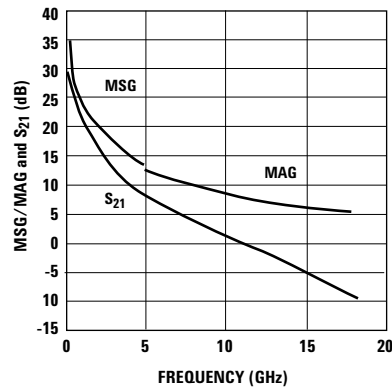


Figure 21. MSG/MAG and  $|S_{21}|^2$  vs. Frequency at 3V, 80 mA.



# ATF-54143 Typical Scattering Parameters, $V_{DS} = 4V$ , $I_{DS} = 60\text{ mA}$

| Freq.<br>GHz | $S_{11}$ |        |       | $S_{21}$ |        | $S_{12}$ |        | $S_{22}$ |        | MSG/MAG<br>dB |
|--------------|----------|--------|-------|----------|--------|----------|--------|----------|--------|---------------|
|              | Mag.     | Ang.   | dB    | Mag.     | Ang.   | Mag.     | Ang.   | Mag.     | Ang.   |               |
| 0.1          | 0.99     | -18.6  | 28.88 | 27.80    | 167.8  | 0.01     | 80.1   | 0.58     | -12.6  | 34.44         |
| 0.5          | 0.81     | -80.2  | 26.11 | 20.22    | 128.3  | 0.03     | 52.4   | 0.42     | -52.3  | 28.29         |
| 0.9          | 0.71     | -117.3 | 23.01 | 14.15    | 106.4  | 0.04     | 41.7   | 0.31     | -73.3  | 25.49         |
| 1.0          | 0.69     | -123.8 | 22.33 | 13.07    | 102.4  | 0.04     | 40.2   | 0.29     | -76.9  | 25.14         |
| 1.5          | 0.64     | -149.2 | 19.49 | 9.43     | 86.2   | 0.05     | 36.1   | 0.22     | -89.4  | 22.76         |
| 1.9          | 0.62     | -164.5 | 17.75 | 7.72     | 75.7   | 0.06     | 34.0   | 0.18     | -95.5  | 21.09         |
| 2.0          | 0.61     | -167.8 | 17.36 | 7.38     | 73.3   | 0.06     | 33.5   | 0.18     | -97.0  | 20.90         |
| 2.5          | 0.60     | 176.6  | 15.66 | 6.07     | 61.9   | 0.07     | 30.7   | 0.14     | -104.0 | 19.38         |
| 3.0          | 0.60     | 162.6  | 14.23 | 5.15     | 51.1   | 0.07     | 27.3   | 0.11     | -113.4 | 18.67         |
| 4.0          | 0.62     | 137.4  | 11.91 | 3.94     | 30.9   | 0.09     | 18.7   | 0.07     | -154.7 | 15.46         |
| 5.0          | 0.65     | 115.9  | 10.00 | 3.16     | 11.7   | 0.10     | 9.0    | 0.09     | 152.5  | 13.20         |
| 6.0          | 0.68     | 97.6   | 8.36  | 2.62     | -6.6   | 0.11     | -1.4   | 0.12     | 127.9  | 11.73         |
| 7.0          | 0.70     | 80.6   | 7.01  | 2.24     | -24.3  | 0.12     | -12.9  | 0.15     | 106.9  | 10.47         |
| 8.0          | 0.72     | 62.6   | 5.76  | 1.94     | -42.3  | 0.13     | -24.7  | 0.17     | 78.9   | 9.31          |
| 9.0          | 0.76     | 45.4   | 4.60  | 1.70     | -60.5  | 0.14     | -36.1  | 0.23     | 56.8   | 8.69          |
| 10.0         | 0.83     | 28.5   | 3.28  | 1.46     | -79.6  | 0.15     | -51.8  | 0.32     | 42.1   | 9.88          |
| 11.0         | 0.86     | 14.1   | 1.87  | 1.24     | -97.0  | 0.15     | -65.4  | 0.41     | 29.4   | 9.17          |
| 12.0         | 0.88     | -0.4   | 0.69  | 1.08     | -112.8 | 0.15     | -78.0  | 0.47     | 16.0   | 8.57          |
| 13.0         | 0.90     | -14.9  | -0.39 | 0.96     | -130.2 | 0.15     | -92.2  | 0.51     | -1.1   | 8.06          |
| 14.0         | 0.87     | -31.4  | -1.72 | 0.82     | -148.8 | 0.15     | -107.3 | 0.58     | -17.6  | 4.90          |
| 15.0         | 0.88     | -46.0  | -3.38 | 0.68     | -166.0 | 0.14     | -121.2 | 0.63     | -32.6  | 3.86          |
| 16.0         | 0.88     | -54.8  | -5.17 | 0.55     | 179.8  | 0.13     | -132.2 | 0.69     | -43.7  | 2.65          |
| 17.0         | 0.87     | -62.8  | -6.73 | 0.46     | 168.4  | 0.12     | -142.3 | 0.72     | -54.2  | 1.33          |
| 18.0         | 0.92     | -73.7  | -7.93 | 0.40     | 154.3  | 0.11     | -155.6 | 0.75     | -67.2  | 2.26          |

## Typical Noise Parameters, $V_{DS} = 4V$ , $I_{DS} = 60\text{ mA}$

| Freq<br>GHz | $F_{min}$<br>dB | $\Gamma_{opt}$<br>Mag. | $\Gamma_{opt}$<br>Ang. | $R_n/50$ | $G_a$<br>dB |
|-------------|-----------------|------------------------|------------------------|----------|-------------|
| 0.5         | 0.17            | 0.33                   | 34.30                  | 0.03     | 28.02       |
| 0.9         | 0.25            | 0.31                   | 60.30                  | 0.04     | 24.12       |
| 1.0         | 0.27            | 0.31                   | 68.10                  | 0.04     | 23.43       |
| 1.9         | 0.45            | 0.27                   | 115.00                 | 0.04     | 18.72       |
| 2.0         | 0.49            | 0.27                   | 119.80                 | 0.04     | 18.35       |
| 2.4         | 0.56            | 0.26                   | 143.50                 | 0.04     | 16.71       |
| 3.0         | 0.63            | 0.28                   | 176.80                 | 0.04     | 15.58       |
| 3.9         | 0.73            | 0.35                   | -145.90                | 0.05     | 13.62       |
| 5.0         | 0.96            | 0.47                   | -116.20                | 0.11     | 12.25       |
| 5.8         | 1.20            | 0.52                   | -98.80                 | 0.19     | 11.23       |
| 6.0         | 1.23            | 0.54                   | -96.90                 | 0.21     | 11.02       |
| 7.0         | 1.33            | 0.60                   | -77.40                 | 0.38     | 9.94        |
| 8.0         | 1.66            | 0.63                   | -56.20                 | 0.64     | 8.81        |
| 9.0         | 1.71            | 0.71                   | -38.60                 | 0.99     | 8.22        |
| 10.0        | 1.85            | 0.82                   | -21.30                 | 1.51     | 8.12        |

Notes:

1.  $F_{min}$  values at 2 GHz and higher are based on measurements while the  $F_{min}$ s below 2 GHz have been extrapolated. The  $F_{min}$  values are based on a set of 16 noise figure measurements made at 16 different impedances using an ATN NP5 test system. From these measurements a true  $F_{min}$  is calculated. Refer to the noise parameter application section for more information.
2. S and noise parameters are measured on a microstrip line made on 0.025 inch thick alumina carrier. The input reference plane is at the end of the gate lead. The output reference plane is at the end of the drain lead. The parameters include the effect of four plated through via holes connecting source landing pads on top of the test carrier to the microstrip ground plane on the bottom side of the carrier. Two 0.020 inch diameter via holes are placed within 0.010 inch from each source lead contact point, one via on each side of that point.

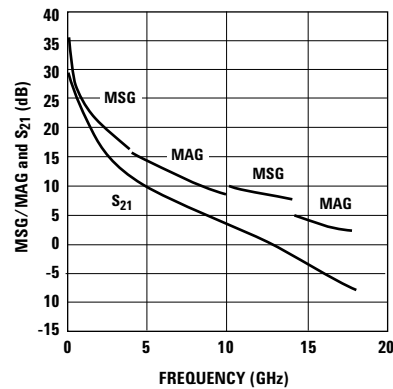


Figure 22. MSG/MAG and  $|S_{21}|^2$  vs. Frequency at 4V, 60 mA.



$I_{BB}$  is the current flowing through the R1/R2 resistor voltage divider network. The values of resistors R1 and R2 are calculated with the following formulas

$$R1 = \frac{V_{gs}}{I_{BB}} \quad (2)$$

$$R2 = \frac{(V_{ds} - V_{gs}) R1}{V_{gs}} \quad (3)$$

### Example Circuit

$$V_{DD} = 5V$$

$$V_{ds} = 3V$$

$$I_{ds} = 60mA$$

$$V_{gs} = 0.59V$$

Choose  $I_{BB}$  to be at least 10X the normal expected gate leakage current.  $I_{BB}$  was chosen to be 2 mA for this example. Using equations (1), (2), and (3) the resistors are calculated as follows

$$R1 = 295\Omega$$

$$R2 = 1205\Omega$$

$$R3 = 32.3\Omega$$

### Active Biasing

Active biasing provides a means of keeping the quiescent bias point constant over temperature and constant over lot to lot variations in device dc performance. The advantage of the active biasing of an enhancement mode PHEMT versus a depletion mode PHEMT is that a negative power source is not required. The techniques of active biasing an enhancement mode device are very similar to those used to bias a bipolar junction transistor.

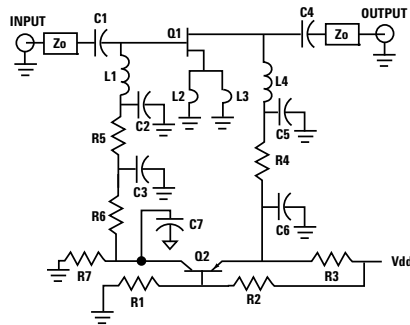


Figure 24. Typical ATF-54143 LNA with Active Biasing.

An active bias scheme is shown in Figure 24. R1 and R2 provide a constant voltage source at the base of a PNP transistor at Q2. The constant voltage at the base of Q2 is raised by 0.7 volts at the emitter. The constant emitter voltage plus the regulated  $V_{DD}$  supply are present across resistor R3. Constant voltage across R3 provides a constant current supply for the drain current. Resistors R1 and R2 are used to set the desired  $V_{ds}$ . The

combined series value of these resistors also sets the amount of extra current consumed by the bias network. The equations that describe the circuit's operation are as follows.

$$V_E = V_{ds} + (I_{ds} \cdot R4) \quad (1)$$

$$R3 = \frac{V_{DD} - V_E}{I_{ds}} \quad (2)$$

$$V_B = V_E - V_{BE} \quad (3)$$

$$V_B = \frac{R1}{R1 + R2} V_{DD} \quad (4)$$

$$V_{DD} = I_{BB} (R1 + R2) \quad (5)$$

Rearranging equation (4) provides the following formula:

$$R2 = \frac{R1 (V_{DD} - V_B)}{V_B} \quad (4A)$$

and rearranging equation (5) provides the following formula:

$$R1 = \frac{V_{DD}}{I_{BB} \left( 1 + \frac{V_{DD} - V_B}{V_B} \right)} \quad (5A)$$

### Example Circuit

$$V_{DD} = 5V$$

$$V_{ds} = 3V$$

$$I_{ds} = 60mA$$

$$R4 = 10\Omega$$

$$V_{BE} = 0.7V$$

Equation (1) calculates the required voltage at the emitter of the PNP transistor based on desired  $V_{ds}$  and  $I_{ds}$  through resistor R4 to be 3.6V. Equation (2) calculates the value of resistor R3 which determines the drain current  $I_{ds}$ . In the example  $R3=23.3\Omega$ . Equation (3) calculates the voltage required at the junction of resistors R1 and R2. This voltage plus the step-up of the base emitter junction determines the regulated  $V_{ds}$ . Equations (4) and (5) are solved simultaneously to determine the value of resistors R1 and R2. In the example  $R1=1450\Omega$  and  $R2=1050\Omega$ . R7 is chosen to be  $1k\Omega$ . This resistor keeps a small amount of current flowing through Q2 to help maintain bias stability. R6 is chosen to be  $10k\Omega$ . This value of resistance is necessary to limit Q1 gate current in the presence of high RF drive level (especially when Q1 is driven to  $P_{1dB}$  gain compression point).

MESFETM1

$$R_f =$$

Gscap=2

 $C_{gs} = 1.73 \text{ pF}$  $C_{gd} = 0.255 \text{ pF}$ 

Gdcap=2

 $E_c = 0.65$  $B_{ad} = 0.25$  $R_{gd}=1.0125 \text{ Ohm}$ 

Rd=1.0125 Ohm  
Rg=1.0 Ohm

Rg=1.0 Uhm  
Re=0.2275 Uhm

 $R_s = 0.3375 \text{ Ohm}$ 
$$L_d =$$
 $L_g = 0.18 \text{ nH}$ 

Ls=

 $C_{ds} = 0.27 \text{ pF}$  $R_c = 250 \, \Omega$ 
$$N =$$

$F_{nc}=1$  MHz

R=0.08

P=0.2

 $C=0.1$ 

Taumdl=no

$w\backslash gfw d=$

wvgIwd-  
wByas=

$$WBvgS=$$

$$wBvgd=$$
$$WBvgd = wBvdo =$$

WBVds=

wldsmx=

wPmax=

AllParams

Eg=

[illegible]

## Designing with S and Noise Parameters and the Non-Linear Model

The non-linear model describing the ATF-54143 includes both the die and associated package model. The package model includes the effect of the pins but does not include the effect of the additional source inductance associated with grounding the source leads through the printed circuit board. The device S and Noise Parameters do include the effect of 0.020 inch thickness printed circuit board vias. When comparing simulation results between the measured S parameters and the simulated non-linear model, be sure to include the effect of the printed circuit board to get an accurate comparison. This is shown schematically in Figure 25.

## For Further Information

The information presented here is an introduction to the use of the ATF-54143 enhancement mode PHEMT. More detailed application circuit information is available from Avago Technologies. Consult the web page or your local Avago Technologies sales representative.

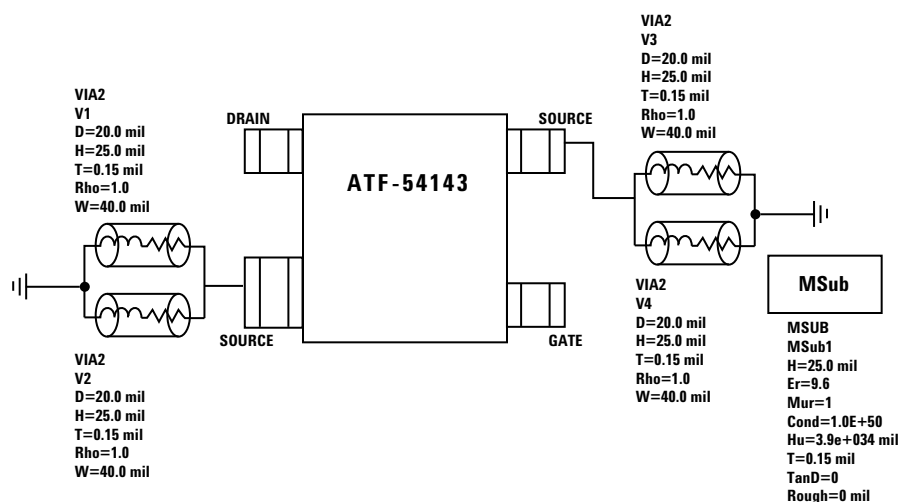


Figure 25. Adding Vias to the ATF-54143 Non-Linear Model for Comparison to Measured S and Noise Parameters.

## Noise Parameter Applications Information

$F_{min}$  values at 2 GHz and higher are based on measurements while the  $F_{min}$ s below 2 GHz have been extrapolated. The  $F_{min}$  values are based on a set of 16 noise figure measurements made at 16 different impedances using an ATN NP5 test system. From these measurements, a true  $F_{min}$  is calculated.  $F_{min}$  represents the true minimum noise figure of the device when the device is presented with an impedance matching network that transforms the source impedance, typically 50 $\Omega$ , to an impedance represented by the reflection coefficient  $\Gamma_o$ . The designer must design a matching network that will present  $\Gamma_o$  to the device with minimal associated circuit losses. The noise figure of the completed amplifier is equal to the noise figure of the device plus the losses of the matching network preceding the device. The noise figure of the device is equal to  $F_{min}$  only when the device is presented with  $\Gamma_o$ . If the reflection coefficient of the matching network is other than  $\Gamma_o$ , then the noise figure of the device will be greater than  $F_{min}$  based on the following equation.

$$NF = F_{min} + \frac{4 R_n}{Z_o} \frac{|\Gamma_s - \Gamma_o|^2}{(1 + |\Gamma_o|^2)(1 - |\Gamma_s|^2)}$$

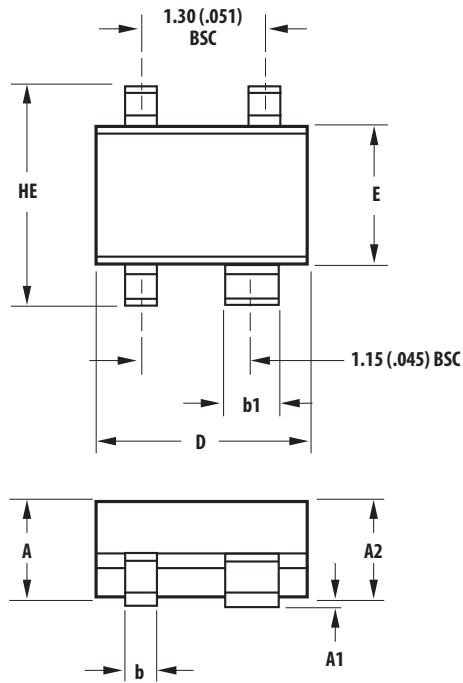
Where  $R_n/Z_o$  is the normalized noise resistance,  $\Gamma_o$  is the optimum reflection coefficient required to produce  $F_{min}$  and  $\Gamma_s$  is the reflection coefficient of the source impedance actually presented to the device. The losses of the matching networks are non-zero and they will also add to the noise figure of the device creating a higher amplifier noise figure. The losses of the matching networks are related to the Q of the components and associated printed circuit board loss.  $\Gamma_o$  is typically fairly low at higher frequencies and increases as frequency is lowered. Larger gate width devices will typically have a lower  $\Gamma_o$  as compared to narrower gate width devices.

Typically for FETs, the higher  $\Gamma_o$  usually infers that an impedance much higher than 50 $\Omega$  is required for the device to produce  $F_{min}$ . At VHF frequencies and even lower L Band frequencies, the required impedance can be in the vicinity of several thousand ohms. Matching to such a high impedance requires very hi-Q components in order to minimize circuit losses. As an example at 900 MHz, when airwound coils (Q>100) are used for matching networks, the loss can still be up to 0.25 dB which will add directly to the noise figure of the device. Using multilayer molded inductors with Qs in the 30 to 50 range results in additional loss over the airwound coil. Losses as high as 0.5 dB or greater add to the typical 0.15 dB  $F_{min}$  of the device creating an amplifier noise figure of nearly 0.65 dB. A discussion concerning calculated and measured circuit losses and their effect on amplifier noise figure is covered in Avago Technologies Application 1085.

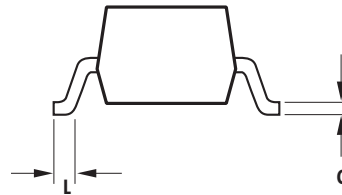
## Ordering Information

| Part Number    | No. of Devices | Container      |
|----------------|----------------|----------------|
| ATF-54143-TR1G | 3000           | 7" Reel        |
| ATF-54143-TR2G | 10000          | 13" Reel       |
| ATF-54143-BLKG | 100            | antistatic bag |

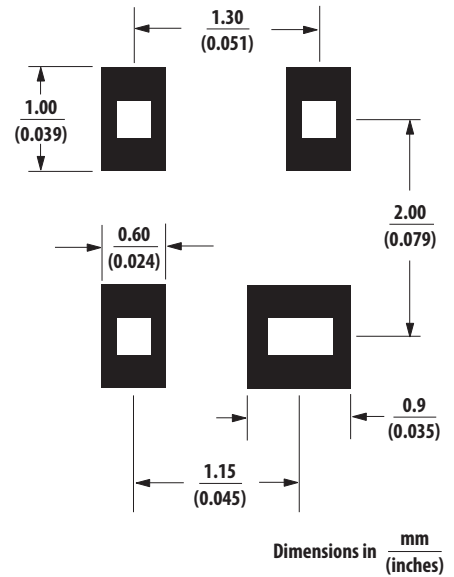
## Package Dimensions Outline 43 (S0%-343/SC70 4 lead)



| SYMBOL | DIMENSIONS (mm) |      |
|--------|-----------------|------|
|        | MIN.            | MAX. |
| E      | 1.15            | 1.35 |
| D      | 1.85            | 2.25 |
| HE     | 1.80            | 2.40 |
| A      | 0.80            | 1.10 |
| A2     | 0.80            | 1.00 |
| A1     | 0.00            | 0.10 |
| b      | 0.15            | 0.40 |
| b1     | 0.55            | 0.70 |
| c      | 0.10            | 0.20 |
| L      | 0.10            | 0.46 |



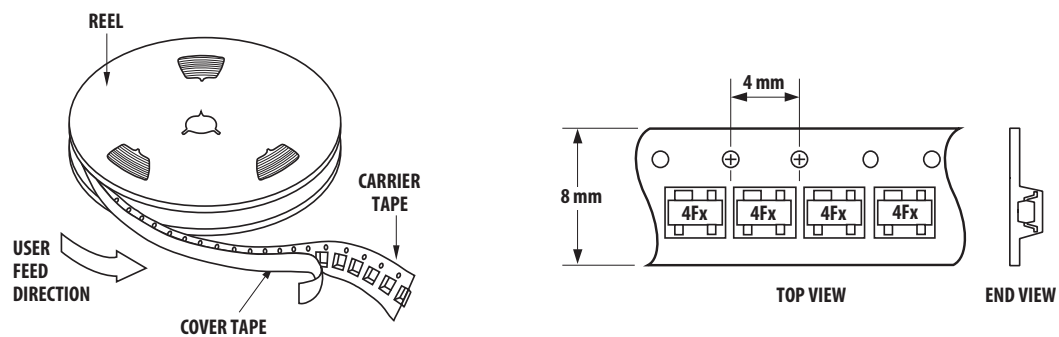
## Recommended PCB Pad Layout for Avago's SC70 4L/SOT-343 Products



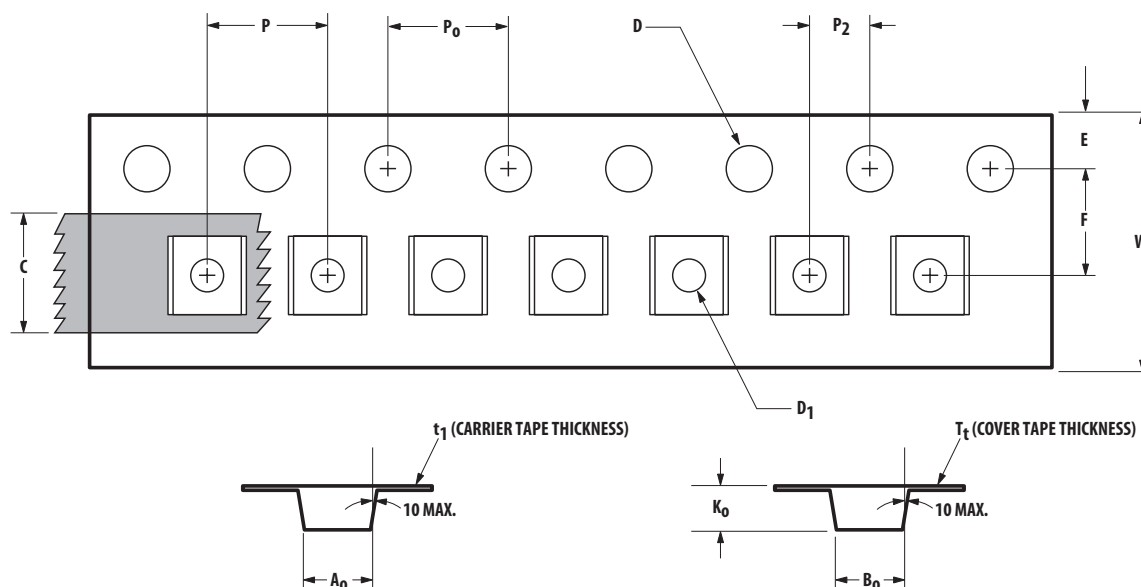
### NOTES:

1. All dimensions are in mm.
2. Dimensions are inclusive of plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. All specifications comply to EIAJ SC70.
5. Die is facing up for mold and facing down for trim/form, ie: reverse trim/form.
6. Package surface to be mirror finish.

## Device Orientation



## Tape Dimensions For Outline 4T



|              | DESCRIPTION                              | SYMBOL         | SIZE (mm)          | SIZE (INCHES)   |
|--------------|--|----------------|--------------------|-----------------|
| CAVITY       | LENGTH                                   | A <sub>0</sub> | 2.40 ± 0.10        | 0.094 ± 0.004   |
|              | WIDTH                                    | B <sub>0</sub> | 2.40 ± 0.10        | 0.094 ± 0.004   |
|              | DEPTH                                    | K <sub>0</sub> | 1.20 ± 0.10        | 0.047 ± 0.004   |
|              | PITCH                                    | P              | 4.00 ± 0.10        | 0.157 ± 0.004   |
|              | BOTTOM HOLE DIAMETER                     | D <sub>1</sub> | 1.00 ± 0.25        | 0.039 ± 0.010   |
| PERFORATION  | DIAMETER                                 | D              | 1.55 ± 0.10        | 0.061 ± 0.002   |
|              | PITCH                                    | P <sub>0</sub> | 4.00 ± 0.10        | 0.157 ± 0.004   |
|              | POSITION                                 | E              | 1.75 ± 0.10        | 0.069 ± 0.004   |
| CARRIER TAPE | WIDTH                                    | W              | 8.00 ± 0.30 - 0.10 | 0.315 ± 0.012   |
|              | THICKNESS                                | t <sub>1</sub> | 0.254 ± 0.02       | 0.0100 ± 0.0008 |
| COVER TAPE   | WIDTH                                    | C              | 5.40 ± 0.10        | 0.205 ± 0.004   |
|              | TAPE THICKNESS                           | T <sub>t</sub> | 0.062 ± 0.001      | 0.0025 ± 0.0004 |
| DISTANCE     | CAVITY TO PERFORATION (WIDTH DIRECTION)  | F              | 3.50 ± 0.05        | 0.138 ± 0.002   |
|              | CAVITY TO PERFORATION (LENGTH DIRECTION) | P <sub>2</sub> | 2.00 ± 0.05        | 0.079 ± 0.002   |

For product information and a complete list of distributors, please go to our web site: [www.avagotech.com](http://www.avagotech.com)

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